PLASTIC SILICON RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 1.5 A

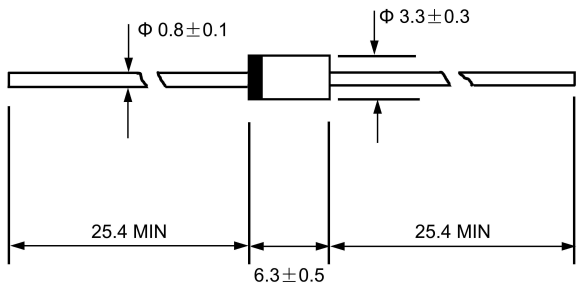
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon,Alcohol,Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case:JEDEC DO-15,molded plastic
- ◇ Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces0.39 grams
- ◇ Mounting position: Any

DO - 15



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		1N 5391	1N 5392	1N 5393	1N 5394	1N 5395	1N 5396	1N 5397	1N 5398	1N 5399	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	300	400	500	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	210	280	350	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	300	400	500	600	800	1000	V
Maximum average forw ard rectified current 9.5mm lead length, @T_A=75℃	$I_{F(AV)}$	1.5									A
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load @T_J=125℃	I_{FSM}	50.0									A
Maximum instantaneous forw ard voltage @ 1.5 A	V_F	1.1									V
Maximum reverse current @T_A=25℃	I_R	5.0									μA
at rated DC blocking voltage @T_A=100℃		50.0									
Typical junction capacitance (Note1)	C_J	20									pF
Typical thermal resistance (Note2)	$R_{\theta JA}$	40									℃/W
Operating junction temperature range	T_J	- 55 ---- + 125									℃
Storage temperature range	T_{STG}	- 55 ---- + 150									℃

NOTE: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Thermal resistance from junction to ambient.

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FIG.1 – TYPICAL FORWARD CHARACTERISTIC

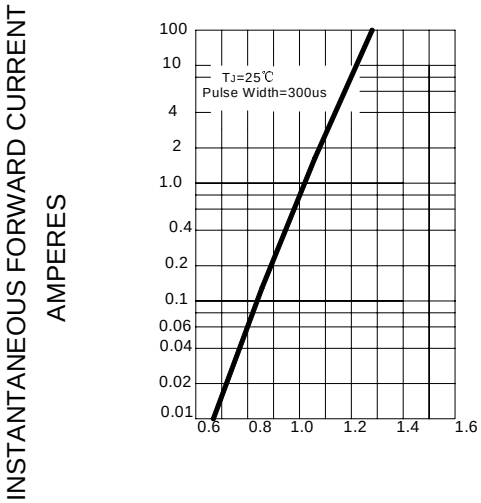

FIG.2 – TYPICAL JUNCTION CAPACITANCE

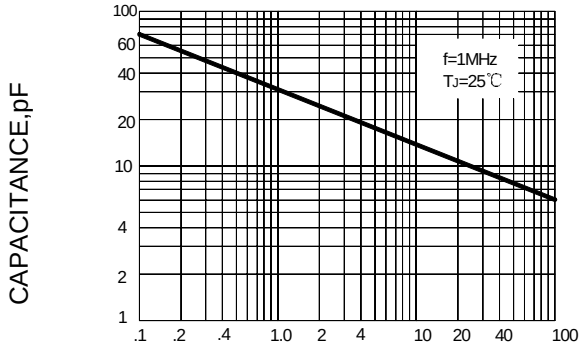

FIG.3 – PEAK FORWARD SURGE CURRENT

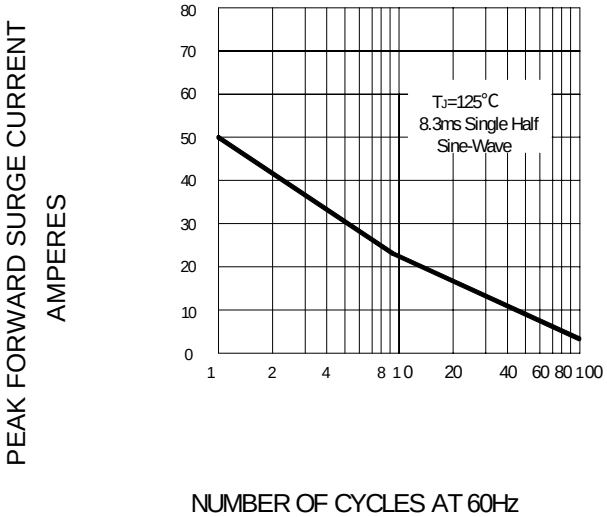

FIG.4 – FORWARD DERATING CURVE